

ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-40°C to +125°C
Operating Temperature	-25°C to +100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	70V
Emitter-collector Voltage BV_{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW

POWER DISSIPATION

Total Power Dissipation	170mW
(derate linearly 2.67mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.65	V	$I_F = 50mA$
	Reverse Current (I_R)			10	μA	$V_R = 4V$
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	70			V	$I_C = 1mA$
	Emitter-collector Breakdown (BV_{ECO}) Collector-emitter Dark Current (I_{CEO})	6		50	V nA	$I_E = 100\mu A$ $V_{CE} = 10V$
Coupled	Current Transfer Ratio (CTR) (Note 2) IS201, ISD201, ISQ201	75			%	10mA I_F , 10V V_{CE}
	IS201, ISD201, ISQ201	10			%	1mA I_F , 10V V_{CE}
	IS202, ISD202, ISQ202	125		250	%	10mA I_F , 10V V_{CE}
	IS202, ISD202, ISQ202	30			%	1mA I_F , 10V V_{CE}
	IS203, ISD203, ISQ203	225		450	%	10mA I_F , 10V V_{CE}
	IS203, ISD203, ISQ203	50			%	1mA I_F , 10V V_{CE}
	IS204, ISD204, ISQ204	200		400	%	10mA I_F , 10V V_{CE}
	IS204, ISD204, ISQ204	100			%	1mA I_F , 10V V_{CE}
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$		0.2	0.4	V	10mA I_F , 2mA I_C
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 1
		7500			V_{PK}	See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500V$ (note 1)
	Output Turn on Time t_{ON}			3.0	μs	$I_F = 10mA$
	Output Turn off Time t_{OFF}			2.5	μs	$V_{CE} = 5V$, $R_L = 75\Omega$

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

